

The gas-phase structure of the decasilsesquioxane $\text{Si}_{10}\text{O}_{15}\text{H}_{10}$

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Supplementary Information

Table S1 Experimental parameters for the GED analysis of $\text{Si}_{10}\text{O}_{15}\text{H}_{10}$.^a

Nozzle-to-film distance	253.55	93.83
T_{nozzle}	423	453
T_{sample}	413	433
Δs	1	2
s_{min}	3.0	10.2
sw_1	4.0	12.0
sw_2	12.0	36.2
s_{max}	13.0	38.0
Correlation parameter	0.497	0.491
Scale factor, k	0.808(4)	0.808(10)

^a Distances in mm, s values in nm^{-1} and temperatures, T , in K. Values in parentheses are estimated standard deviations of the last digits.

Table S2 Calculated [MP2/6-311++G(3df,3pd)] coordinates (Å) for Si₁₀O₁₅H₁₀.

	<i>x</i>	<i>y</i>	<i>Z</i>
Si(1)	−2.5540	0.8298	1.5843
Si(2)	0.0000	2.6854	1.5843
Si(3)	2.5540	0.8298	1.5843
Si(4)	1.5785	−2.1726	1.5843
Si(5)	−1.5785	−2.1726	1.5843
Si(6)	−2.5540	0.8298	−1.5843
Si(7)	−1.5785	−2.1726	−1.5843
Si(8)	1.5785	−2.1726	−1.5843
Si(9)	2.5540	0.8298	−1.5843
Si(10)	0.0000	2.6854	−1.5843
O(11)	0.0000	−2.2571	1.9581
O(12)	1.3267	1.8260	1.9581
O(13)	−1.3267	1.8260	−1.9581
O(14)	−2.1466	−0.6975	−1.9581
O(15)	0.0000	−2.2571	−1.9581
O(16)	2.1466	−0.6975	−1.9581
O(17)	1.3267	1.8260	−1.9581
H(18)	2.3029	−3.1696	2.3574
H(19)	3.7261	1.2107	2.3574
H(20)	3.7261	1.2107	−2.3574
H(21)	2.3029	−3.1696	−2.3574
H(22)	−2.3029	−3.1696	−2.3574
H(23)	−3.7261	1.2107	−2.3574
O(24)	0.0000	3.0566	0.0000
O(25)	−2.9070	0.9445	0.0000
O(26)	−1.7966	−2.4728	0.0000
O(27)	1.7966	−2.4728	0.0000
O(28)	2.9070	0.9445	0.0000
H(29)	0.0000	3.9179	−2.3574
O(30)	2.1466	−0.6975	1.9581
O(31)	−1.3267	1.8260	1.9581
H(32)	0.0000	3.9179	2.3574
O(33)	−2.1466	−0.6975	1.9581
H(34)	−3.7261	1.2107	2.3574
H(35)	−2.3029	−3.1696	2.3574

Energy (not zero-point corrected) = −4025.01654 Hartrees.

Table S3 Refined and calculated RMS amplitudes of vibration (u), associated r_a distances and corresponding distance correction values ($r_a - r_e$) for $\text{Si}_{10}\text{O}_{15}\text{H}_{10}$.^a

	Atom pair	r_a	$u_{\text{(GED)}}$	$r_a - r_e$	$u_{\text{MD(calc.)}}$
u_1	Si(1)–H(34)	146.6(7)	7.7(7)	0.8	7.5
u_2	Si(1)–O(31)	162.5(2)	4.7(1)	0.9	5.0
u_3	Si(1)–O(25)	163.1(3)	4.7(tied to u_2)	0.9	5.0
u_5	H(18)···O(27)	251.0(17)	10.6(tied to u_7)	1.0	9.5
u_4	O(11)···H(18)	253.6(10)	10.9(tied to u_7)	1.4	9.9
u_7	O(11)···O(26)	263.9(2)	9.4(2)	0.3	8.4
u_6	O(11)···O(30)	265.2(4)	9.5(tied to u_7)	0.6	8.6
u_9	Si(1)···Si(2)	310.7(3)	9.0(1)	−4.7	8.6
u_8	Si(1)···Si(6)	312.8(5)	8.7(tied to u_9)	−3.1	8.4
u_{10}	O(24)···O(25)	359.2(14)	35.7(tied to u_{11})	0.7	35.8
u_{12}	O(11)···O(15)	369.9(16)	34.3(tied to u_{11})	−14.3	34.5
u_{11}	Si(1)···O(24)	372.4(7)	19.6(2)	−1.0	19.6
u_{13}	Si(1)···O(13)	375.4(8)	19.6(tied to u_{11})	−8.7	19.7
u_{14}	Si(1)···O(11)	395.2(4)	24.1(tied to u_{11})	−6.2	24.1
u_{15}	Si(1)···H(32)	402.3(9)	17.0(tied to u_{11})	−6.2	17.1
u_{16}	Si(1)···H(23)	409.5(6)	10.9(tied to u_{11})	−1.8	10.9
u_{17}	O(11)···O(12)	414.7(6)	52.1(tied to u_{11})	−13.4	52.3
u_{18}	Si(1)···Si(7)	440.6(2)	12.3(2)	−5.9	10.8
u_{20}	O(11)···O(14)	458.9(13)	43.0(tied to u_{21})	−7.6	31.0
u_{21}	O(11)···O(25)	463.4(6)	40.3(27)	−8.8	29.0
u_{22}	H(18)···H(21)	471.5(41)	22.3(fixed)	3.3	22.3
u_{19}	H(18)···H(19)	467.6(8)	22.3(fixed)	3.3	22.3
u_{23}	H(18)···O(26)	473.7(8)	26.3(tied to u_{28})	−3.7	24.3
u_{25}	Si(1)···O(30)	483.3(5)	47.0(tied to u_{28})	−11.3	44.2
u_{24}	O(11)···H(21)	486.8(16)	20.8(tied to u_{28})	−6.7	19.3
u_{26}	O(11)···H(19)	501.7(13)	20.7(tied to u_{28})	−9.4	19.2
u_{27}	Si(1)···Si(3)	503.9(5)	22.1(tied to u_{28})	−6.4	20.5
u_{28}	Si(1)···O(15)	520.1(5)	29.4(9)	−11.4	27.2
u_{29}	Si(1)···H(22)	554.9(10)	18.4(tied to u_{31})	−6.1	17.0
u_{30}	O(11)···O(24)	556.3(9)	48.0(tied to u_{31})	−7.4	44.4
u_{32}	O(11)···O(13)	557.4(11)	44.2(tied to u_{31})	−17.8	40.9
u_{31}	Si(1)···O(27)	565.8(11)	26.0(6)	−2.0	24.0
u_{33}	O(24)···O(26)	584.0(22)	28.2(tied to u_{31})	3.9	26.1
u_{35}	Si(1)···O(16)	591.5(5)	38.2(tied to u_{31})	−13.4	35.3
u_{34}	Si(1)···Si(8)	592.4(2)	18.2(tied to u_{31})	−7.9	16.8
u_{36}	O(11)···H(32)	603.6(14)	50.8(tied to u_{31})	−15.5	46.9
u_{37}	Si(1)···H(18)	623.1(13)	25.2(tied to u_{31})	−11.2	23.3
u_{38}	H(18)···H(20)	652.4(20)	24.3(fixed)	−5.1	24.3
u_{39}	O(11)···H(20)	652.0(10)	28.0(fixed)	−12.1	28.0
u_{40}	H(18)···O(24)	698.3(14)	25.7(fixed)	−5.7	25.7
u_{41}	Si(1)···H(20)	731.6(8)	18.5(fixed)	−10.2	18.5
u_{42}	H(18)···H(32)	729.9(28)	24.9(fixed)	−16.9	24.9
u_{43}	O(11)···H(29)	735.1(9)	36.0(fixed)	−15.3	36.1

u_{44}	H(18)···H(23)	868.8(15)	20.8(fixed)	-12.6	20.8
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^a Distances in pm. Values in parentheses are the standard deviations on the last digits. See Figure 1 for atom numbering.

Table S4 GED-determined coordinates (Å) for Si₁₀O₁₅H₁₀.

	<i>x</i>	<i>y</i>	<i>z</i>
Si(1)	-2.1708	1.5772	1.5797
Si(2)	0.8292	2.5520	1.5797
Si(3)	2.6833	0.0000	1.5797
Si(4)	0.8292	-2.5520	1.5797
Si(5)	-2.1708	-1.5772	1.5797
Si(6)	-2.1708	1.5772	-1.5797
Si(7)	-2.1708	-1.5772	-1.5797
Si(8)	0.8292	-2.5520	-1.5797
Si(9)	2.6833	0.0000	-1.5797
Si(10)	0.8292	2.5520	-1.5797
O(11)	-0.6954	-2.1404	1.9209
O(12)	1.8207	1.3228	1.9209
O(13)	-0.6954	2.1404	-1.9209
O(14)	-2.2505	0.0000	-1.9209
O(15)	-0.6954	-2.1404	-1.9209
O(16)	1.8207	-1.3228	-1.9209
O(17)	1.8207	1.3228	-1.9209
H(18)	1.2132	-3.7338	2.3412
H(19)	3.9260	0.0000	2.3412
H(20)	3.9260	0.0000	-2.3412
H(21)	1.2132	-3.7338	-2.3412
H(22)	-3.1762	-2.3076	-2.3412
H(23)	-3.1762	2.3076	-2.3412
O(24)	0.9424	2.9003	0.0000
O(25)	-2.4672	1.7925	0.0000
O(26)	-2.4672	-1.7925	0.0000
O(27)	0.9424	-2.9003	0.0000
O(28)	3.0496	0.0000	0.0000
H(29)	1.2132	3.7338	-2.3412
O(30)	1.8207	-1.3228	1.9209
O(31)	-0.6954	2.1404	1.9209
H(32)	1.2132	3.7338	2.3412
O(33)	-2.2505	0.0000	1.9209
H(34)	-3.1762	2.3076	2.3412
H(35)	-3.1762	-2.3076	2.3412

Table S5 Least-squares correlation matrix ($\times 100$) for the GED refinement of $\text{Si}_{10}\text{O}_{15}\text{H}_{10}$.^a

	p_5	u_{21}	u_{28}	u_{32}	k_2
p_4	-87	68	63		
p_4		-65	-67		
u_2					75
u_{21}			64		
u_{28}				62	

^a Only absolute values ≥ 50 are shown. k_2 is a scale factor.

Figure S1 Molecular-intensity scattering and difference (experimental minus theoretical) curves for $\text{Si}_{10}\text{O}_{15}\text{H}_{10}$.

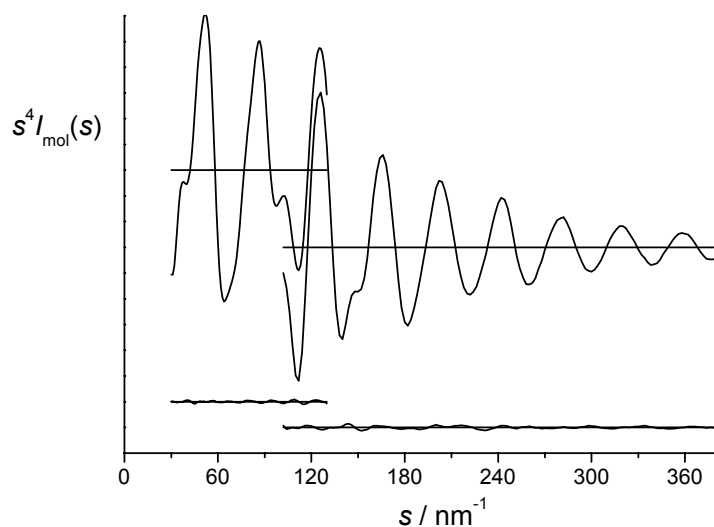


Figure S2 Eigenvector diagram [RHF/6-31G(d)] showing the vibrational motions associated with the 17 cm^{-1} mode.

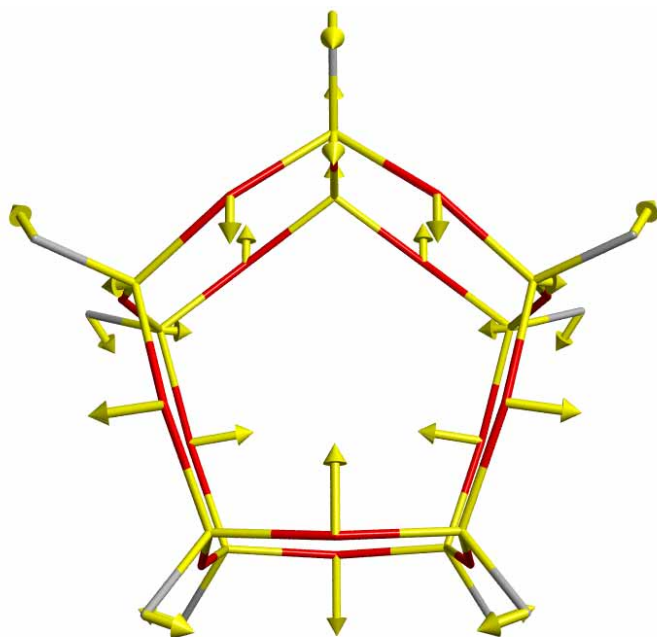


Figure S3 Eigenvector diagram [RHF/6-31G(d)] showing the vibrational motions associated with the 22 cm^{-1} mode.

